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Vishay Semiconductors

AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN

FREE

GREEN

(5-2008)

Power SMD LED PLCC-2 Plus



DESCRIPTION

The VLMR51.., VLMK51.., and VLMY51.. LED series in PLCC2 plus package are an advanced product in terms of high luminous flux and low thermal resistance.

In combination with the small package outline (3.5 mm x 3.5 mm x 1.2 mm) the PLCC2 plus is an ideal choice for backlighting, signage, exterior and interior automotive lighting as well as decorative lighting.

PRODUCT GROUP AND PACKAGE DATA

• Product group: LED

Package: SMD PLCC-2 plus
Product series: power
Angle of half intensity: ± 60°

FEATURES

- High efficient AllnGaP technology
- Compact package outline 3.5 mm x 3.5 mm x 1.2 mm
- Angle of half intensity $\varphi = \pm 60^{\circ}$
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit $\phi_{min.}/\phi_{max.} < 1.6$
- ESD-withstand voltage: Up to 2 kV (HBM) according to JESD22-A114-B
- Preconditioning according to JEDEC® level 2a
- Compatible with IR-reflow soldering profiles according to J-STD-020
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Interior and exterior automotive lighting: Dashboard, brake lights, turn lights, backlighting
- Signal and symbol luminaire
- · Decorative lighting
- Architectural lighting
- Backlighting: LCDs, switches, keys, illuminated advertising
- Marker lights
- · Traffic lights

PARTS TABLE														
PART	COLOR		JMINOU ITENSIT (mcd)		at I _F (mA)	WA	VELEN((nm)	ЭТН	at I _F (mA)	FORWARD VOLTAGE (V)		at I _F (mA)	TECHNOLOGY	
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		
VLMR51Z1AA-GS08	Red	4500	7100	9000	140	620	-	630	140	1.9	2.2	2.65	140	AllnGaP on Si
VLMK51Z1AA-GS08	Amber	4500	7100	9000	140	610	-	621	140	1.9	2.2	2.65	140	AllnGaP on Si
VLMY51Z1AA-GS08	Yellow	4500	7100	9000	140	585	-	594	140	1.9	2.2	2.65	140	AllnGaP on Si

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) VLMR51, VLMK51, VLMY51							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage	I _R = 10 μA	V_{R}	12	V			
DC forward current		I _F	200	mA			
Surge forward current	t _p ≤ 10 μs	I _{FSM}	1000	mA			
Power dissipation		P _V	530	mW			
Junction temperature		Tj	125	°C			
Operating temperature range		T _{amb}	- 40 to + 110	°C			
Storage temperature range		T _{stg}	- 40 to + 110	°C			
Thermal resistance junction/solder point		R _{thJS}	50	K/W			
Thermal resistance junction/ambient	Mounted on PCB, total Cu area > 900 mm ²	R _{thJA}	100	K/W			



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OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) VLMR51, RED								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Luminous intensity	I _F = 140 mA	VLMR51Z1AA	l _V	4500	7100	9000	mcd	
Luminous flux	I _F = 140 mA	VLMR51Z1AA	φ _V	-	20	-	lm	
Dominant wavelength	I _F = 140 mA		λ_{d}	620	-	630	nm	
Angle of half intensity	I _F = 140 mA		φ	-	± 60	-	deg	
Forward voltage	I _F = 140 mA		V _F	1.9	2.2	2.65	V	
Temperature coefficient I _V	I _F = 140 mA, 0 °C ≤ T ≤ 100 °C		TC _{IV}	-	- 26.8	-	mcd/K	
Temperature coefficient V _F	I _F = 140 mA, 0 °C ≤ T ≤ 100 °C		TC _V	-	- 3.5	-	mV/K	
Temperature coefficient λ _d	I _E = 140 mA. 0 °C < T < 100 °C		TCad	-	0.06	_	nm/K	

Note

• Forward voltages are tested using a current pulse of 1 ms and has an accuracy of \pm 0.1 V

OPTICAL AND ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) VLMK51, AMBER								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Luminous intensity	I _F = 140 mA	VLMK51Z1AA	l _V	4500	7100	9000	mcd	
Luminous flux	I _F = 140 mA	VLMK51Z1AA	φ _V	-	20	-	lm	
Dominant wavelength	I _F = 140 mA		λ_{d}	610	-	621	nm	
Angle of half intensity	I _F = 140 mA		φ	-	± 60	-	deg	
Forward voltage	I _F = 140 mA		V _F	1.9	2.2	2.65	V	
Temperature coefficient I _V	$I_F = 140 \text{ mA}, 0 \text{ °C} \le T \le 100 \text{ °C}$		TC _{IV}	-	- 35.3	-	mcd/K	
Temperature coefficient V _F	I _F = 140 mA, 0 °C ≤ T ≤ 100 °C		TC _V	=	- 2.9	-	mV/K	
Temperature coefficient λ_d	I _F = 140 mA, 0 °C ≤ T ≤ 100 °C		$TC_{\lambda d}$	-	0.07	-	nm/K	

Note

 $\bullet~$ Forward voltages are tested using a current pulse of 1 ms and has an accuracy of $\pm~0.1~\text{V}$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified) VLMY51, YELLOW								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Luminous intensity	I _F = 140 mA	VLMY51Z1AA	l _V	4500	7100	9000	mcd	
Luminous flux	I _F = 140 mA	VLMY51Z1AA	φ _V	-	20	-	lm	
Dominant wavelength	I _F = 140 mA		λ_{d}	585	-	594	nm	
Angle of half intensity	I _F = 140 mA		φ	ı	± 60	-	deg	
Forward voltage	I _F = 140 mA		V_{F}	1.9	2.2	2.65	V	
Temperature coefficient I _V	$I_F = 140 \text{ mA}, 0 \text{ °C} \le T \le 100 \text{ °C}$		TC _{IV}	-	- 55.5	-	mcd/K	
Temperature coefficient V _F	$I_F = 140 \text{ mA}, 0 \text{ °C} \le T \le 100 \text{ °C}$		TC _V	-	- 2.9	-	mV/K	
Temperature coefficient λ _d	$I_F = 140 \text{ mA}, 0 \text{ °C} \le T \le 100 \text{ °C}$		$TC_{\lambda d}$	-	0.09	-	nm/K	

Note

Forward voltages are tested using a current pulse of 1 ms and has an accuracy of ± 0.1 V



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LUMINOUS INTENSITY CLASSIFICATION								
GROUP	LIGHT INTENSITY (mcd)							
STANDARD	MIN. MAX.							
Z1	4500	5600						
Z2	5600	7150						
AA	7150	9000						

N	110

 Luminous flux is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION								
	DOM. WAVELENGTH (nm)							
GROUP	AMI	AMBER YELLOW						
	MIN.	MAX.	MIN.	MAX.				
W	610	615	-	-				
Х	615	621	585	588				
Y	-	-	588	591				
Z	-	-	591	594				

Note

 Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

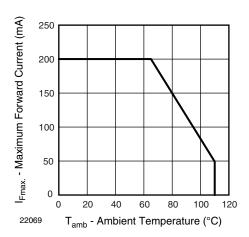


Fig. 1 - Forward Current vs. Ambient Temperature

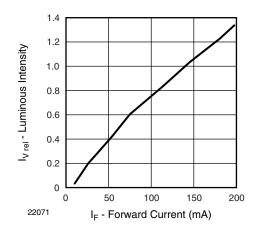


Fig. 3 - Relative Luminous Intensity vs. Forward Current

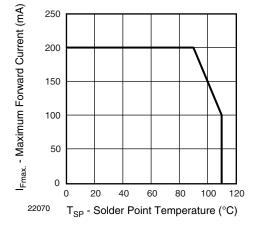


Fig. 2 - Maximum Forward Current vs. Solder Point Temperature

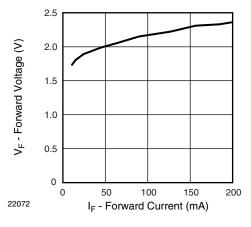


Fig. 4 - Relative Forward Voltage vs. Forward Current





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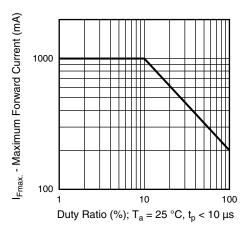


Fig. 5 - Forward Current vs. Duty Ratio

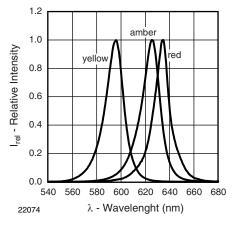


Fig. 6 - Relative Intensity vs. Wavelength

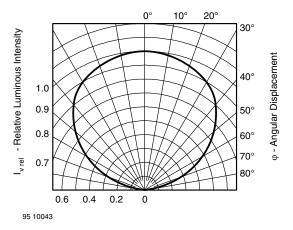
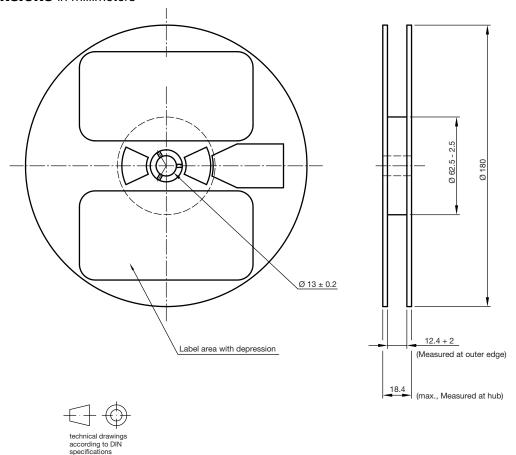


Fig. 7 - Relative Luminous Intensity vs. Angular Displacement



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REEL DIMENSIONS in millimeters



Not indicated tolerances \pm 0.5 Material: black static dissipative

GS08 = 1000 pcs

Drawing-No.: 9.800-5104.01-4

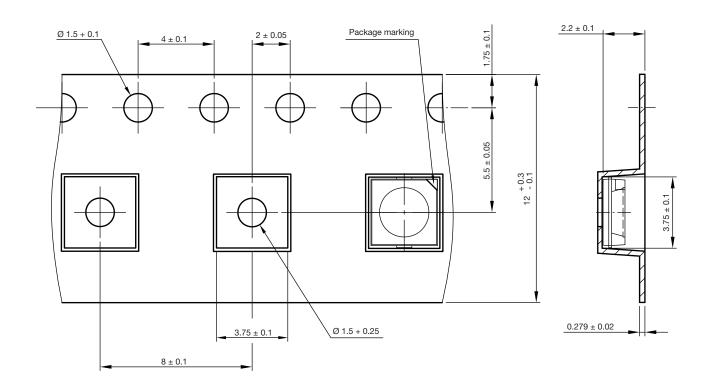
Issue: 2; 19.03.10

22067

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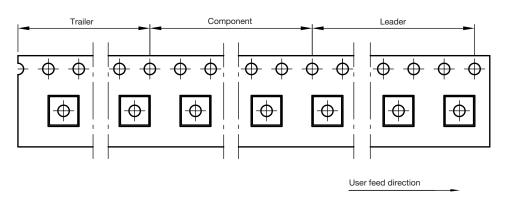
TAPING AND ORIENTATION DIMENSIONS in millimeters

Reels come in quantity of 1000 units.



200 mm min. for Ø 180 reel

480 mm min. for Ø 180 reel



Drawing-No.: 9.700-5348.01-4

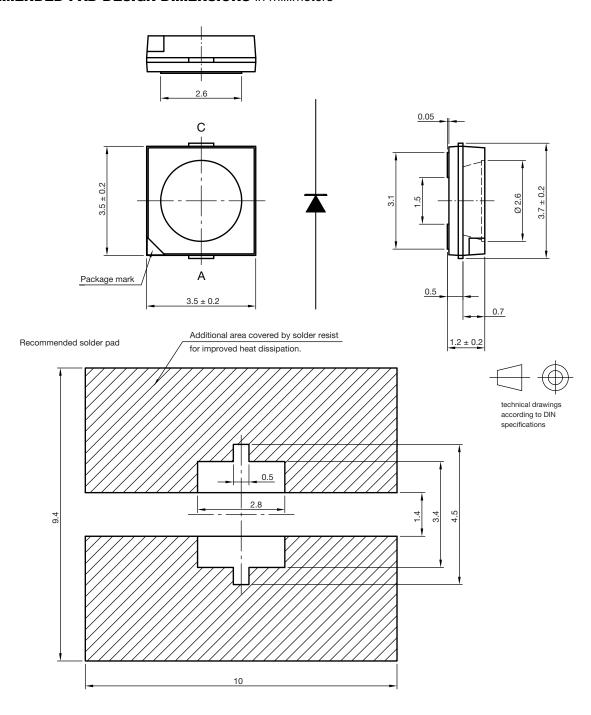
Issue: 1; 01.03.10

22066



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RECOMMENDED PAD DESIGN DIMENSIONS in millimeters



Drawing-No.: 6.541-5084.01-4

Issue: 1; 13.04.10

22103

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SOLDERING PROFILE

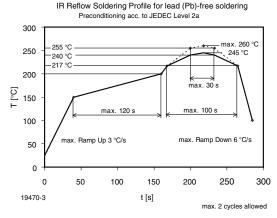
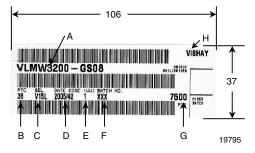


Fig. 8 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

BAR CODE PRODUCT LABEL (example)



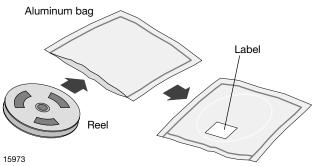
- A) Type of component
- B) Manufacturing plant
- C) SEL selection code (bin):

e.g.: V1 = code for luminous intensity group 5L = code for chrom. coordinate group

- D) Date code year/week
- E) Day code (e.g. 1: Monday)
- F) Batch no.
- G) Total quantity
- H) Company code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

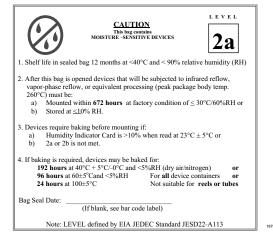
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 Level 2a Label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.



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